VLSI BASED DESIGN OF BULK DRIVEN OPERATION AMPLIFIER

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ABSTRACT

Low-voltage, low-power consumption is a desirable feature for any portable electronic device for longer battery

life, prevent chip overheating, shrinking the battery size and its weight as well. In present paper, Operational Amplifier is

designed using the Bulk-Driven technique, the input signal is applied to the body terminal. This operational amplifier has

been operated at 0.8 V, and consume power 146.789 µW which is less than earlier design. So it can be considered as ultra

Low Voltage, Low Power design.

In the aim to enhance the performance of the proposed Bulk-driven circuit, the self-cascode structure is employed.

The self-cascode structure increases the performance of the circuit furthermore. it is suitable for Low Voltage circuit

designs. Open loop gain is obtained as 87.39 dB with phase margin of 77.25 dB. All simulations of the design are carried

out in the Cadence tool with 0.18 µm Technology.

KEYWORDS: Low-Voltage, VLSI, Operational Amplifier